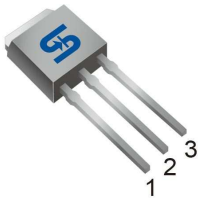
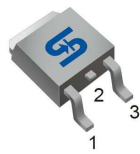




TO-251
(IPAK)



TO-252
(DPAK)



SOT-223



Pin Definition:

1. Gate
2. Drain
3. Source

PRODUCT SUMMARY

V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)
600	10 @ V _{GS} =10V	0.5

General Description

The TSM1NB60 N-Channel Power MOSFET is produced by new advance planar process. This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode.

Features

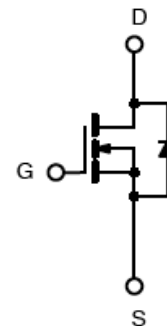
- Low R_{DS(ON)} 8Ω (Typ.)
- Low gate charge typical @ 6.1nC (Typ.)
- Low Crss typical @ 4.2pF (Typ.)

Ordering Information

Part No.	Package	Packing
TSM1NB60CH C5G	TO-251	75pcs / Tube
TSM1NB60CP ROG	TO-252	2.5Kpcs / 13" Reel
TSM1NB60CW RPG	SOT-223	2.5Kpcs / 13" Reel

Note: "G" denotes for Halogen Free

Block Diagram



N-Channel MOSFET

Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

Parameter	Symbol	Limit			Unit
		IPAK	DPAK	SOT-223	
Drain-Source Voltage	V _{DS}	600			V
Gate-Source Voltage	V _{GS}	±30			V
Continuous Drain Current	I _D	1			A
		0.7			A
Pulsed Drain Current *	I _{DM}	4			A
Single Pulse Avalanche Energy (Note 2)	E _{AS}	5			mJ
Peak Diode Recovery dv/dt (Note 3)	dv/dt	4.5			V/ns
Total Power Dissipation @ T _C = 25°C	P _{TOT}	39	39	2.1	W
Operating Junction Temperature	T _J	150			°C
Storage Temperature Range	T _{STG}	-55 to +150			°C

Note: Limited by maximum junction temperature

Thermal Performance

Parameter	Symbol	Limit			Unit
		IPAK	DPAK	SOT-223	
Thermal Resistance - Junction to Case	$R\theta_{JC}$	2.87	2.87	--	$^{\circ}\text{C/W}$
Thermal Resistance - Junction to Ambient	$R\theta_{JA}$	110	110	60	$^{\circ}\text{C/W}$

Electrical Specifications (Ta = 25 $^{\circ}\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$	BV_{DSS}	600	--	--	V
Drain-Source On-State Resistance	$V_{GS} = 10\text{V}, I_D = 0.5\text{A}$	$R_{DS(ON)}$	--	8	10	Ω
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	$V_{GS(TH)}$	2.5	3.5	4.5	V
Zero Gate Voltage Drain Current	$V_{DS} = 600\text{V}, V_{GS} = 0\text{V}$	I_{DSS}	--	--	10	μA
Gate Body Leakage	$V_{GS} = \pm 30\text{V}, V_{DS} = 0\text{V}$	I_{GSS}	--	--	± 100	nA
Forward Transfer Conductance	$V_{DS} = 10\text{V}, I_D = 0.5\text{A}$	g_{fs}	--	0.8	--	S
Dynamic						
Total Gate Charge	$V_{DS} = 480\text{V}, I_D = 1\text{A},$ $V_{GS} = 10\text{V}$ (Note 4,5)	Q_g	--	6.1	--	nC
Gate-Source Charge		Q_{gs}	--	1.4	--	
Gate-Drain Charge		Q_{gd}	--	3.3	--	
Input Capacitance	$V_{DS} = 25\text{V}, V_{GS} = 0\text{V},$ $f = 1.0\text{MHz}$	C_{iss}	--	138	--	pF
Output Capacitance		C_{oss}	--	17.1	--	
Reverse Transfer Capacitance		C_{rss}	--	4.2	--	
Switching						
Turn-On Delay Time	$V_{GS} = 10\text{V}, I_D = 1\text{A},$ $V_{DD} = 300\text{V}, R_G = 25\Omega$ (Note 4,5)	$t_{d(on)}$	--	7.7	--	nS
Turn-On Rise Time		t_r	--	6.8	--	
Turn-Off Delay Time		$t_{d(off)}$	--	15.3	--	
Turn-Off Fall Time		t_f	--	14.9	--	
Source-Drain Diode Ratings and Characteristic						
Source Current	Integral reverse diode in the MOSFET	I_S	--	--	1	A
Source Current (Pulse)		I_{SM}	--	--	4	A
Diode Forward Voltage	$I_S = 1\text{A}, V_{GS} = 0\text{V}$	V_{SD}	--	0.9	1.4	V

Note 1: Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

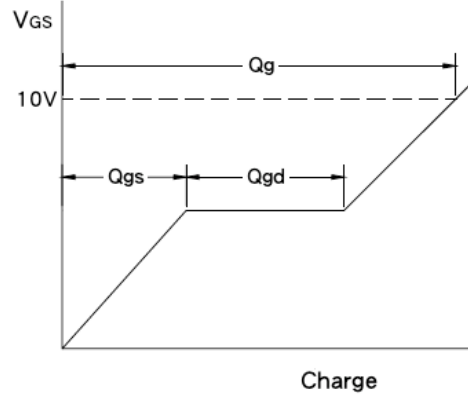
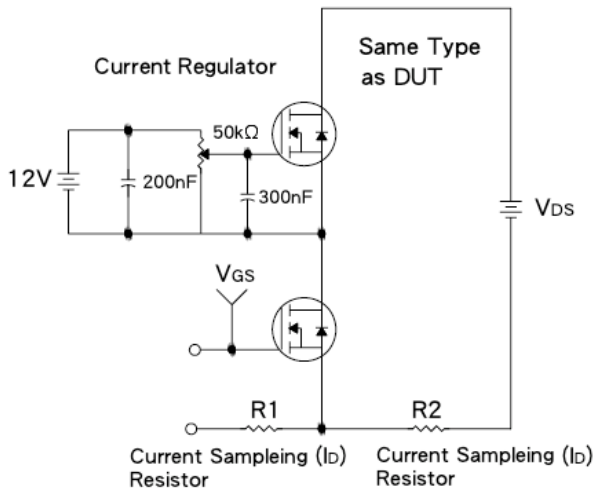
Note 2: $V_{DD} = 50\text{V}, I_{AS} = 1\text{A}, L = 10\text{mH}, R_G = 25\Omega,$ Starting $T_J = 25^{\circ}\text{C}$

Note 3: $I_{SD} \leq 1\text{A}, di/dt \leq 200\text{A}/\mu\text{S}, V_{DD} \leq BV_{DSS},$ Starting $T_J = 25^{\circ}\text{C}$

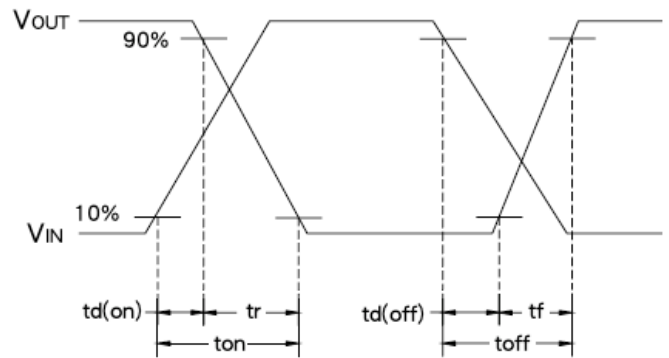
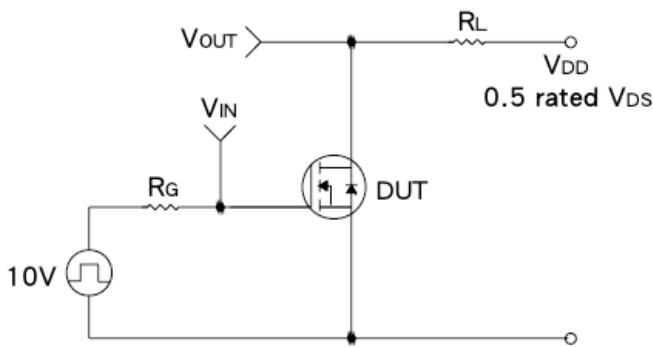
Note 4: Pulse test: pulse width $\leq 300\mu\text{S},$ duty cycle $\leq 2\%$

Note 5: Essentially Independent of Operating Temperature

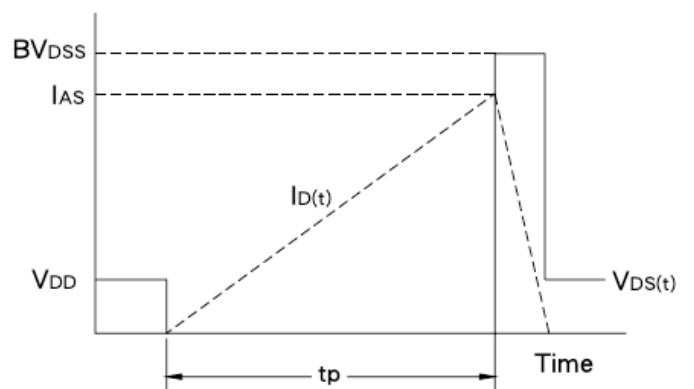
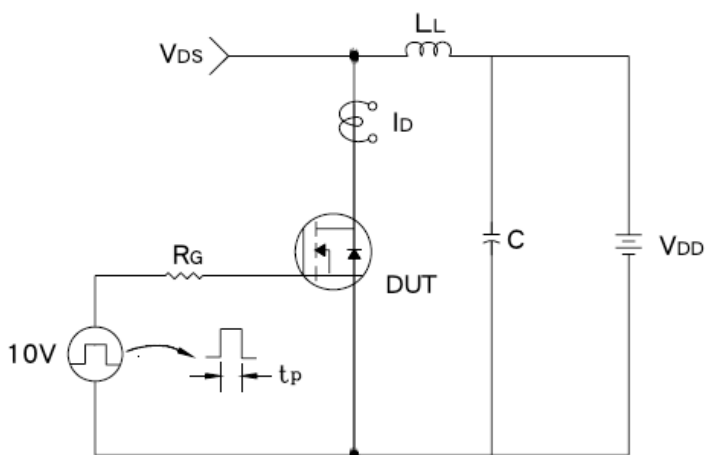
Gate Charge Test Circuit & Waveform



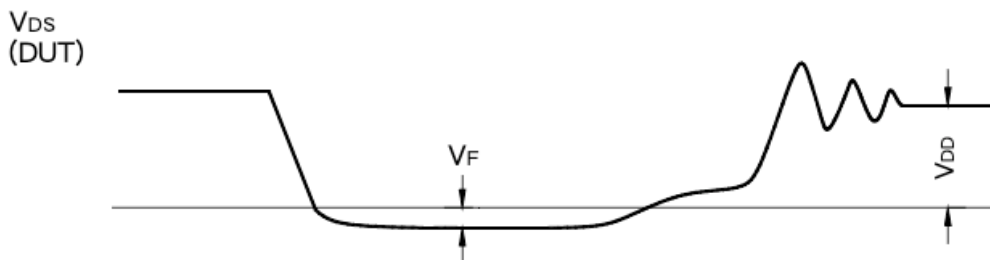
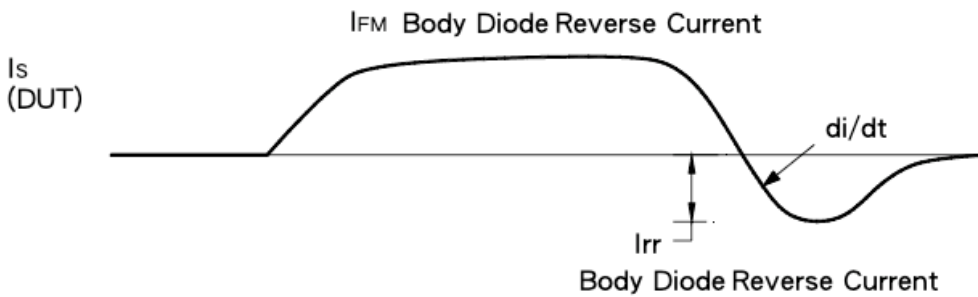
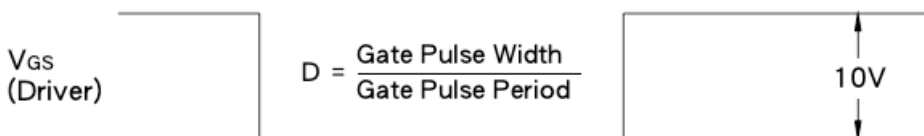
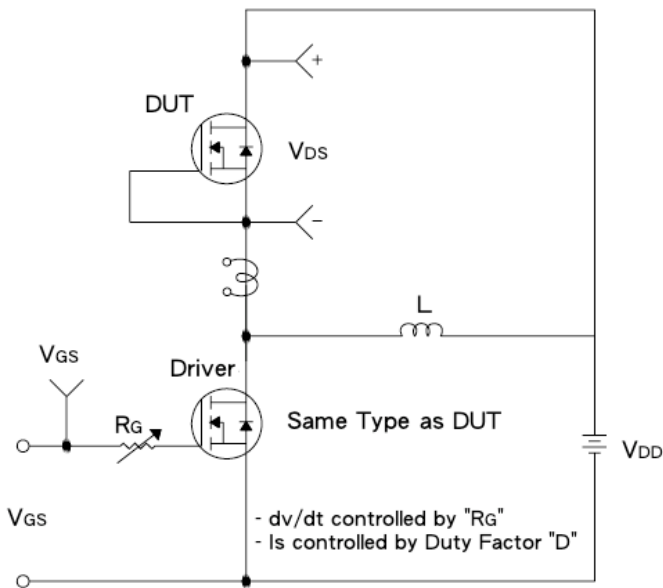
Resistive Switching Test Circuit & Waveform



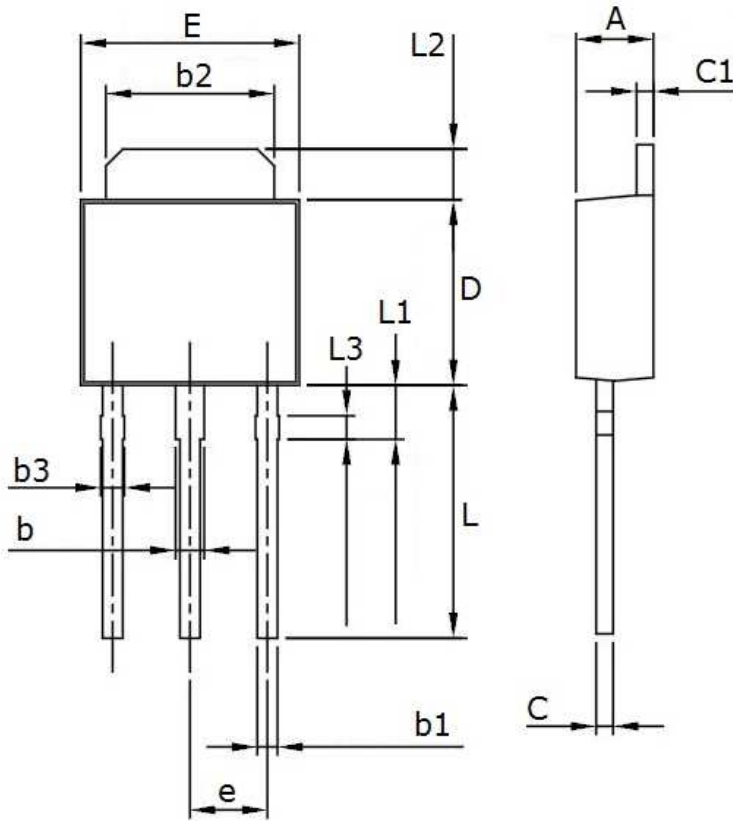
E_{AS} Test Circuit & Waveform



Diode Reverse Recovery Time Test Circuit & Waveform

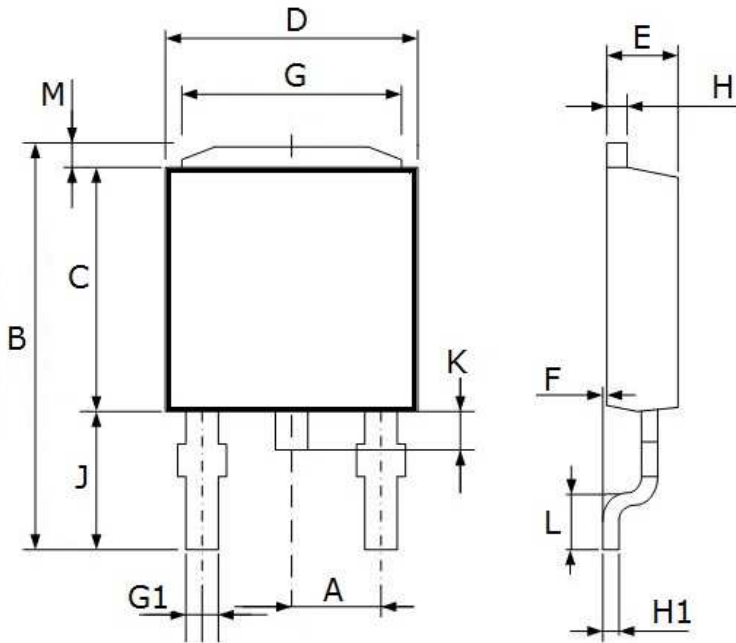


TO-251 Mechanical Drawing



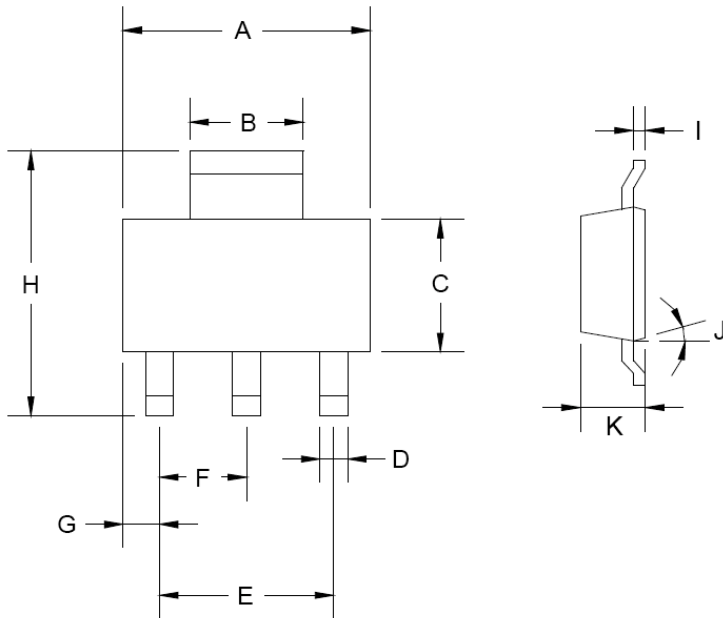
TO-251 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.10	2.50	0.083	0.098
b	0.65	1.05	0.026	0.041
b1	0.58	0.62	0.023	0.024
b2	4.80	5.20	0.189	0.205
b3	0.68	0.72	0.027	0.028
C	0.35	0.65	0.014	0.026
C1	0.40	0.60	0.016	0.024
D	5.30	5.70	0.209	0.224
E	6.30	6.70	0.248	0.264
e	2.30 BSC		0.09 BSC	
L	7.00	8.00	0.276	0.315
L1	1.40	1.80	0.055	0.071
L2	1.30	1.70	0.051	0.067
L3	0.50	0.90	0.020	0.035

TO-252 Mechanical Drawing



TO-252 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.30 BSC		0.090 BSC	
B	10.20	10.80	0.402	0.425
C	5.30	5.70	0.209	0.224
D	6.30	6.70	0.248	0.264
E	2.10	2.50	0.083	0.098
F	0.00	0.20	0.000	0.008
G	4.80	5.20	0.189	0.205
G1	0.40	0.80	0.016	0.031
H	0.40	0.60	0.016	0.024
H1	0.35	0.65	0.014	0.026
J	3.35	3.65	0.132	0.144
K	0.50	1.10	0.020	0.043
L	0.90	1.50	0.035	0.059
M	1.30	1.70	0.051	0.067

SOT-223 Mechanical Drawing



SOT-223 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	6.350	6.850	0.250	0.270
B	2.900	3.100	0.114	0.122
C	3.450	3.750	0.136	0.148
D	0.595	0.635	0.023	0.025
E	4.550	4.650	0.179	0.183
F	2.250	2.350	0.088	0.093
G	0.835	1.035	0.032	0.041
H	6.700	7.300	0.263	0.287
I	0.250	0.355	0.010	0.014
J	10°	16°	10°	16°
K	1.550	1.800	0.061	0.071

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